

c) REMARKS

The claims are 11; 12 and 14-24 with claims 11, 12, 23 and 24 being independent. Support for new claims 23 and 24 is found, inter alia, in compounds (1-1) to (1-27) and in Tables 1 and 2.

In the Advisory Action of March 8, 2004, the Examiner expressed concern for the presence of support for the claimed charge accumulation feature; i.e., the charge generating layer tending to accumulate excess charges upon irradiation with the semiconductor layer exposure light source. On page 11, line 16 to page 12, line 11, the exposure light source irradiating the charge generating material is disclosed and a factor causing defects on exposure is accumulation of exciton and charge carriers (excess charges).

Accordingly, it is respectfully requested that the claims be allowed and that the case be passed to issue.

Applicants' undersigned attorney may be reached in our New York office by telephone at (212) 218-2100. All correspondence should continue to be directed to our below listed address.

Respectfully submitted,

  
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